

N- AND P-CHANNEL ENHANCEMENT MODE POWER MOSFET**L4505**

	N-CH	P-CH
BVDSS	30V	-30V
ID	10A	-8.4A
RDS(on)(max)	14mΩ	20mΩ

Description

The L4505 consists of a N-channel and a P-channel enhancement-mode MOSFET in a single SOP-8 package, providing the designer with the best combination of fast switching, ruggedized device design, low on-resistance and cost-effectiveness.

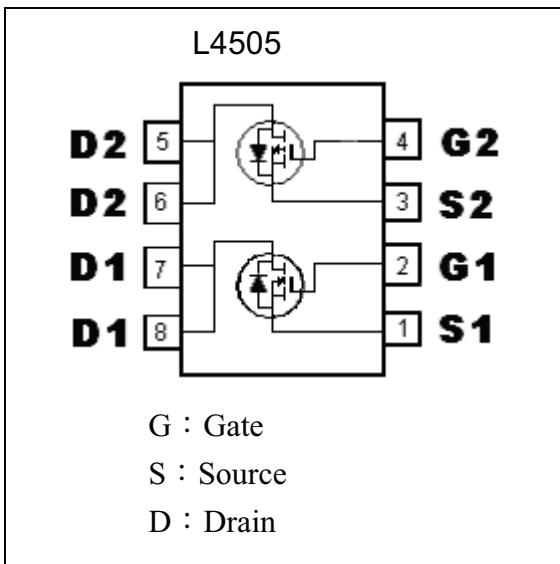
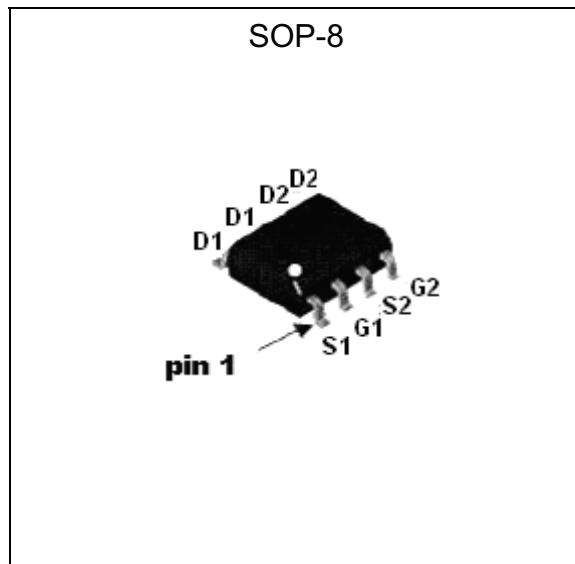
The SOP-8 package is universally preferred for all commercial-industrial surface mount applications and suited for low voltage applications such as DC/DC converters.

Features

- Simple drive requirement
- Low on-resistance
- Fast switching speed
- RoHS compliant package

Applications

- Power management in notebook computer, portable equipment and battery powered systems.
- BLDC Motor Control Application

Equivalent Circuit**Outline**

Absolute Maximum Ratings ($T_c=25^\circ\text{C}$, unless otherwise noted)

Parameter	Symbol	Limits		Unit
		N-channel	P-channel	
Drain-Source Breakdown Voltage	BV_{DSS}	30	-30	V
Gate-Source Voltage	V_{GS}	± 20	± 20	V
Continuous Drain Current @ $T_A=25^\circ\text{C}$ (Note 1)	I_D	10	-8.4	A
Continuous Drain Current @ $T_A=70^\circ\text{C}$ (Note 1)	I_D	7.9	-6.7	A
Pulsed Drain Current (Note 2)	I_{DM}	30	-30	A
Total Power Dissipation @ $T_A=25^\circ\text{C}$ (Note 1)	P_d	2.0		W
Linear Derating Factor		0.016		W / $^\circ\text{C}$
Operating Junction and Storage Temperature Range	T_j, T_{stg}	$-55\text{--}+150$		$^\circ\text{C}$
Thermal Resistance, Junction-to-Ambient (Note 1)	$R_{\text{th},ja}$	62.5		$^\circ\text{C}/\text{W}$

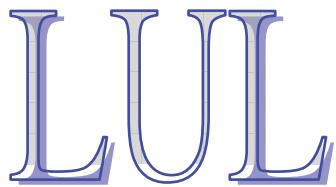
Note : 1.Surface mounted on 1 in² copper pad of FR-4 board, 135°C/W when mounted on minimum copper pad

2.Pulse width limited by maximum junction temperature

N-Channel Electrical Characteristics ($T_j=25^\circ\text{C}$, unless otherwise specified)

Symbol	Min.	Typ.	Max.	Unit	Test Conditions
Static					
BV_{DSS}	30	-	-	V	$\text{V}_{\text{GS}}=0, I_D=250\mu\text{A}$
$\text{BV}_{\text{DSS}}/\Delta T_j$	-	0.02	-	$\text{V}/^\circ\text{C}$	Reference to 25 °C, $I_D=1\text{mA}$
$\text{V}_{\text{GS(th)}}$	1.0	1.5	3.0	V	$\text{V}_{\text{DS}}=\text{V}_{\text{GS}}, I_D=250\mu\text{A}$
I_{GSS}	-	-	± 100	nA	$\text{V}_{\text{GS}}=\pm 20\text{V}, \text{V}_{\text{DS}}=0$
I_{DSS}	-	-	1	μA	$\text{V}_{\text{DS}}=30\text{V}, \text{V}_{\text{GS}}=0$
	-	-	25	μA	$\text{V}_{\text{DS}}=24\text{V}, \text{V}_{\text{GS}}=0, T_j=70^\circ\text{C}$
$*R_{\text{DS(ON)}}$	-	-	14	$\text{m}\Omega$	$I_D=9\text{A}, \text{V}_{\text{GS}}=10\text{V}$
	-	-	20		$I_D=5\text{A}, \text{V}_{\text{GS}}=4.5\text{V}$
$*G_{\text{FS}}$	-	14	-	S	$\text{V}_{\text{DS}}=10\text{V}, I_D=9\text{A}$
Dynamic					
C_{iss}	-	1770	2830	pF	$\text{V}_{\text{DS}}=25\text{V}, \text{V}_{\text{GS}}=0, f=1\text{MHz}$
C_{oss}	-	430	-		
C_{rss}	-	350	-	ns	$\text{V}_{\text{DS}}=15\text{V}, I_D=1\text{A}, \text{V}_{\text{GS}}=10\text{V}, R_G=3.3\Omega, R_D=15\Omega$
$*t_{\text{d(ON)}}$	-	14	-		
$*t_{\text{r}}$	-	10	-		
$*t_{\text{d(OFF)}}$	-	36	-		
$*t_{\text{f}}$	-	17	-		
$*Q_{\text{g}}$	-	23	65	nC	$\text{V}_{\text{DS}}=24\text{V}, I_D=9\text{A}, \text{V}_{\text{GS}}=4.5\text{V}$
$*Q_{\text{gs}}$	-	6	-		
$*Q_{\text{gd}}$	-	14	-		
Source-Drain Diode					
$*V_{\text{SD}}$	-	-	1.2	V	$\text{V}_{\text{GS}}=0\text{V}, I_S=1.7\text{A}$
$*t_{\text{rr}}$	-	31	-	ns	$I_S=9\text{A}, \text{V}_{\text{GS}}=0, dI/dt=100\text{A}/\mu\text{s}$
$*Q_{\text{rr}}$	-	25	-		

*Pulse Test : Pulse Width ≤300μs, Duty Cycle≤2%



L4505

P-Channel Electrical Characteristics (T_j=25°C, unless otherwise specified)

Symbol	Min.	Typ.	Max.	Unit	Test Conditions
Static					
BV _{DSS}	-30	-	-	V	V _{GS} =0, I _D =-250μA
BV _{DSS/ΔTj}	-	-0.02	-	V/°C	Reference to 25 °C, I _D =-1mA
V _{GS(th)}	-1.0	-	-3.0	V	V _{DS} =V _{GS} , I _D =-250μA
I _{GSS}	-	-	±100	nA	V _{GS} =±20V, V _{DS} =0
I _{DSS}	-	-	-1	μA	V _{DS} =-30V, V _{GS} =0
	-	-	-25	μA	V _{DS} =-24V, V _{GS} =0, T _j =70°C
*R _{DSD(ON)}	-	-	20	mΩ	I _D =-8A, V _{GS} =-10V
	-	-	30		I _D =-4A, V _{GS} =-4.5V
*G _{FS}	-	14	-	S	V _{DS} =-10V, I _D =-8A
Dynamic					
C _{iss}	-	1580	2530	pF	V _{DS} =-25V, V _{GS} =0, f=1MHz
C _{oss}	-	540	-		
C _{rss}	-	450	-		
*t _{d(ON)}	-	16	-	ns	V _{DS} =-15V, I _D =-1A, V _{GS} =-10V, R _G =3.3 Ω, R _D =15 Ω
*t _r	-	11	-		
*t _{d(OFF)}	-	40	-		
*t _f	-	25	-		
*Q _g	-	27	45	nC	V _{DS} =-24V, I _D =-8A, V _{GS} =-4.5V
*Q _{gs}	-	4	-		
*Q _{gd}	-	18	-		
Source-Drain Diode					
*V _{SD}	-	-	-1.2	V	V _{GS} =0V, I _s =-1.7A
*trr	-	40	-	ns	I _s =-8A, V _{GS} =0, dI/dt=100A/μs
*Qrr	-	32	-		

*Pulse Test : Pulse Width ≤300μs, Duty Cycle≤2%

Ordering Information

Device	Package	Shipping	Marking
L4505	SOP-8 (RoHS compliant)	3000 pcs / Tape & Reel	4505SS

N-channel Characteristic Curves

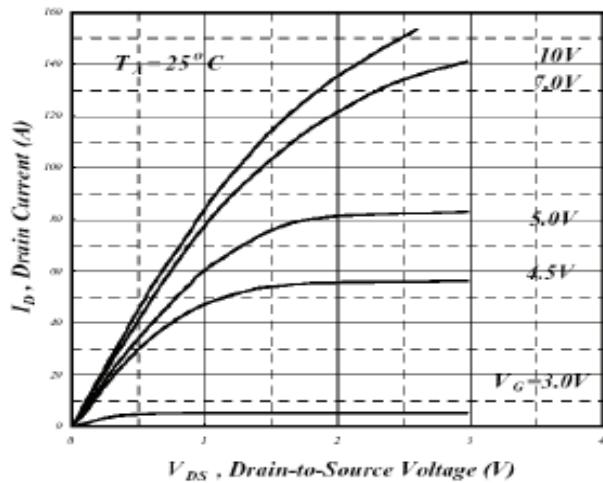


Fig 1. Typical Output Characteristics

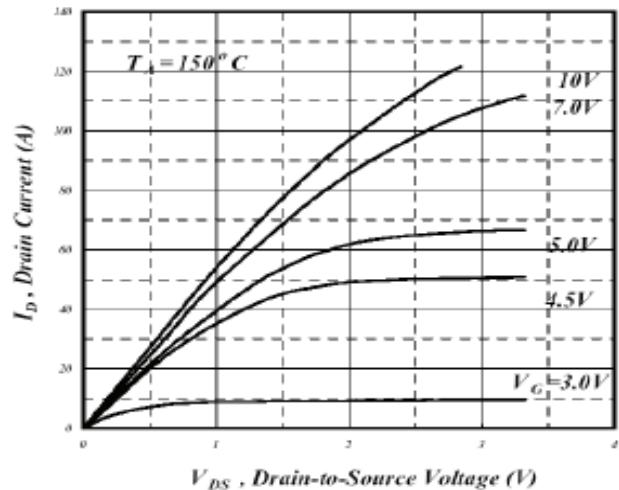


Fig 2. Typical Output Characteristics

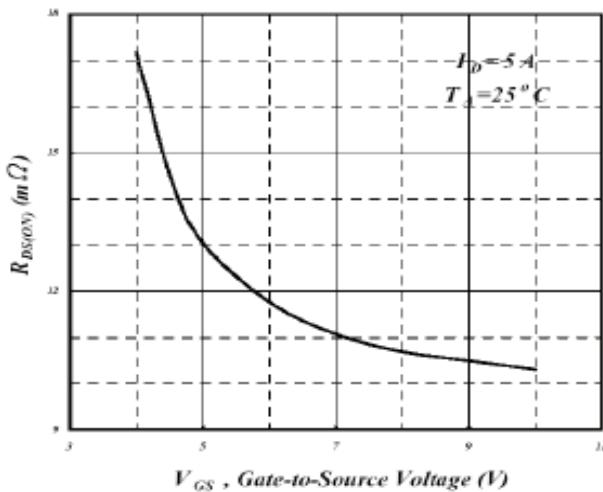


Fig 3. On-Resistance vs. Gate Voltage

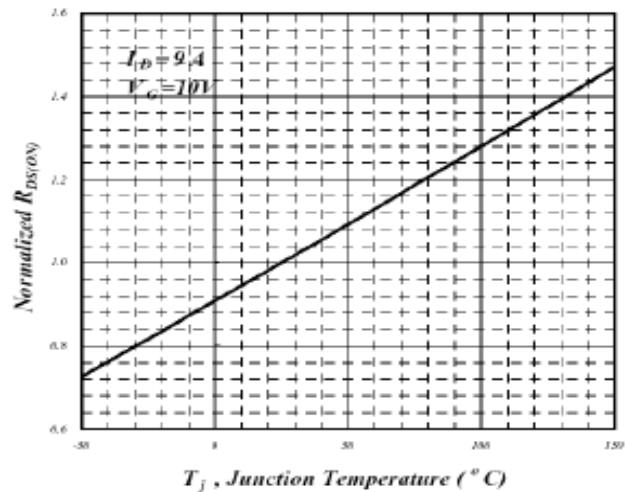


Fig 4. Normalized On-Resistance vs. Junction Temperature

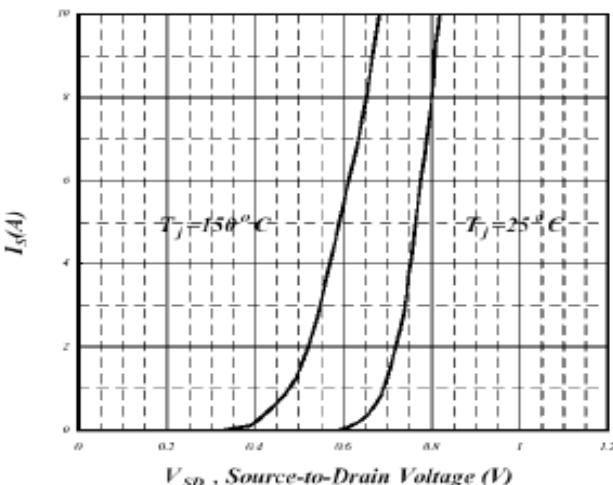


Fig 5. Forward Characteristics of Reverse Diode

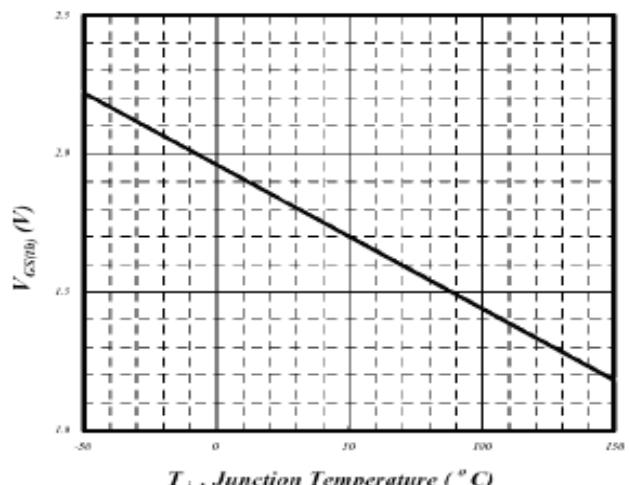


Fig 6. Gate Threshold Voltage vs. Junction Temperature

N-channel Characteristic Curves(Cont.)

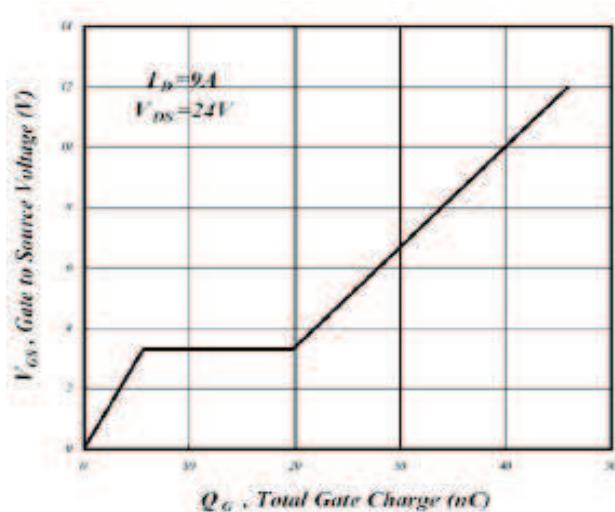


Fig 7. Gate Charge Characteristics

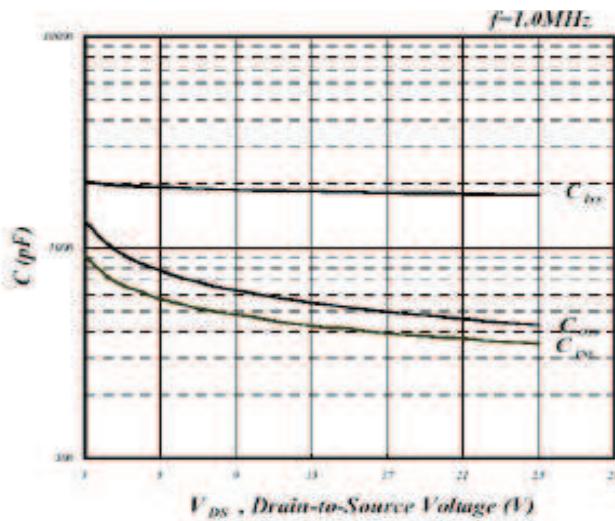


Fig 8. Typical Capacitance Characteristics

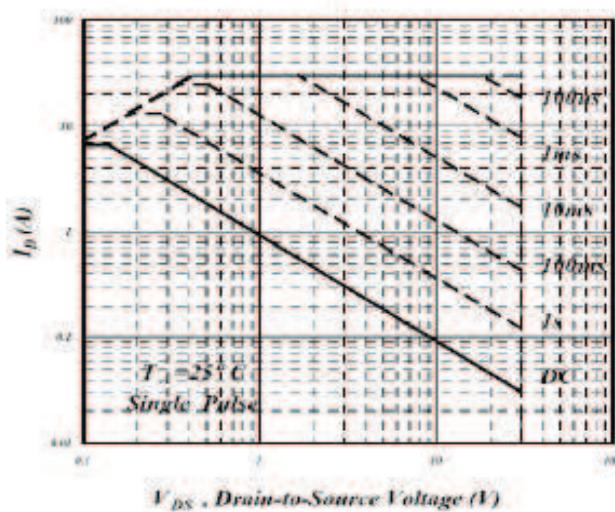


Fig 9. Maximum Safe Operating Area

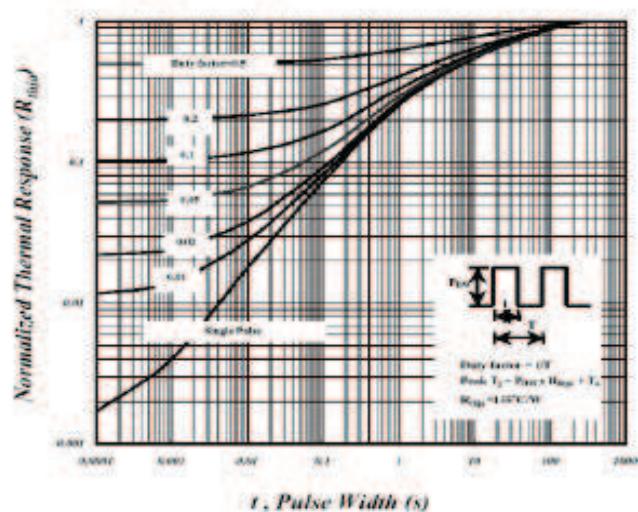


Fig 10. Effective Transient Thermal Impedance

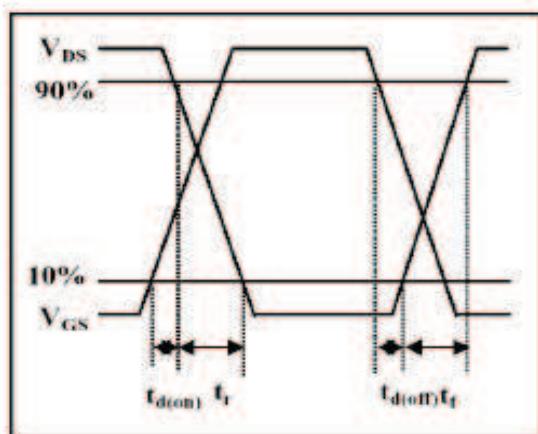


Fig 11. Switching Time Waveform

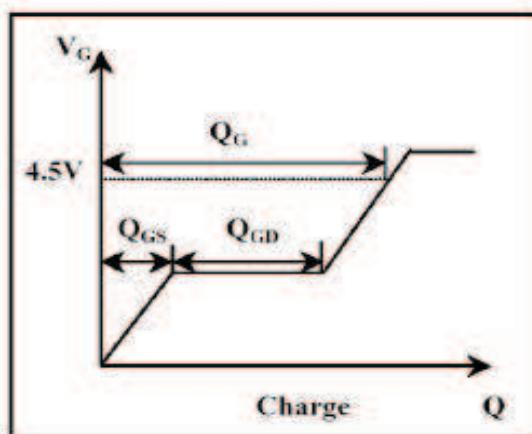


Fig 12. Gate Charge Waveform

P-Channel Characteristic Curves

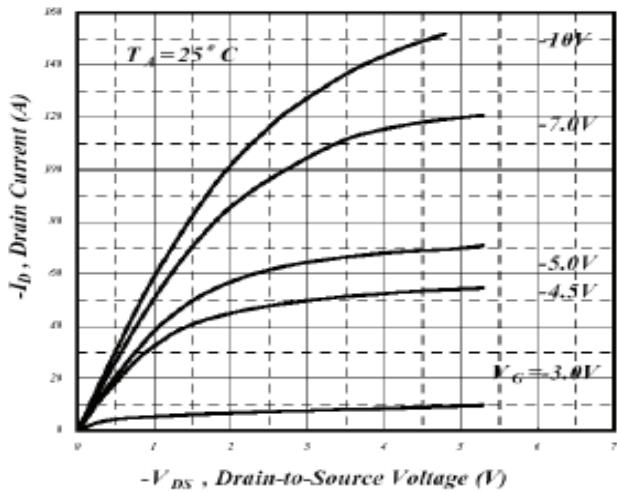


Fig 1. Typical Output Characteristics

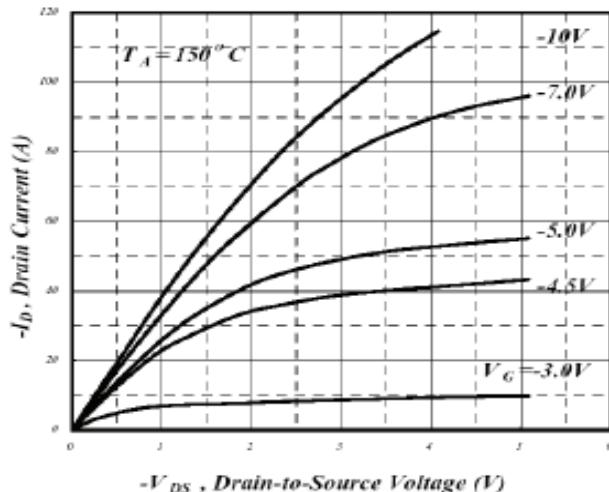


Fig 2. Typical Output Characteristics

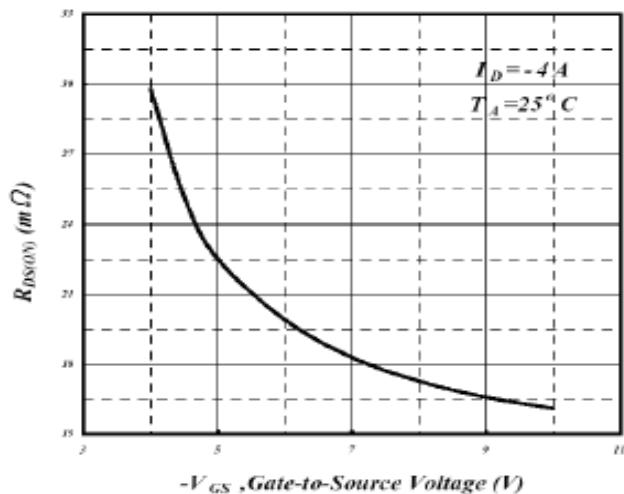


Fig 3. On-Resistance vs. Gate Voltage

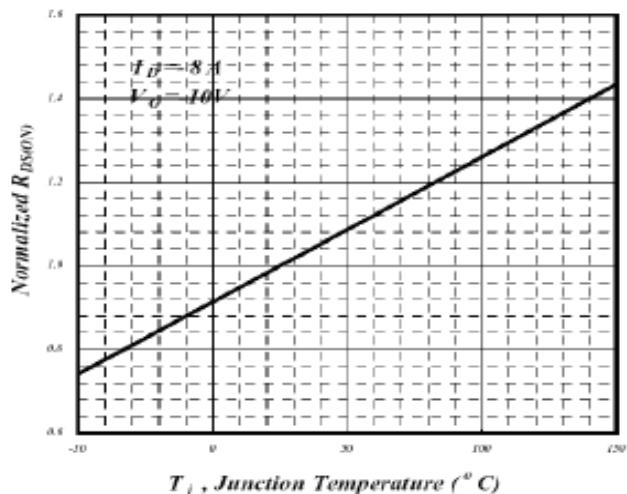


Fig 4. Normalized On-Resistance vs. Junction Temperature

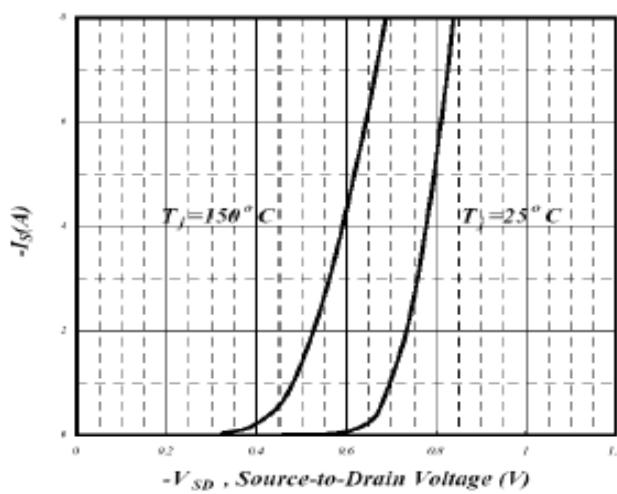


Fig 5. Forward Characteristics of Reverse Diode

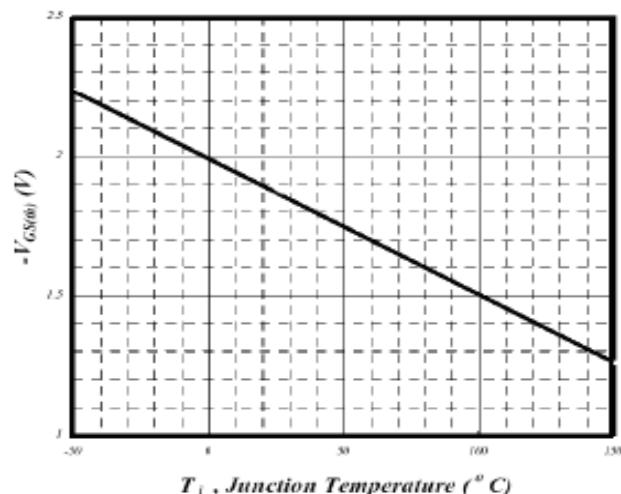


Fig 6. Gate Threshold Voltage vs. Junction Temperature

P-channel Characteristic Curves(Cont.)

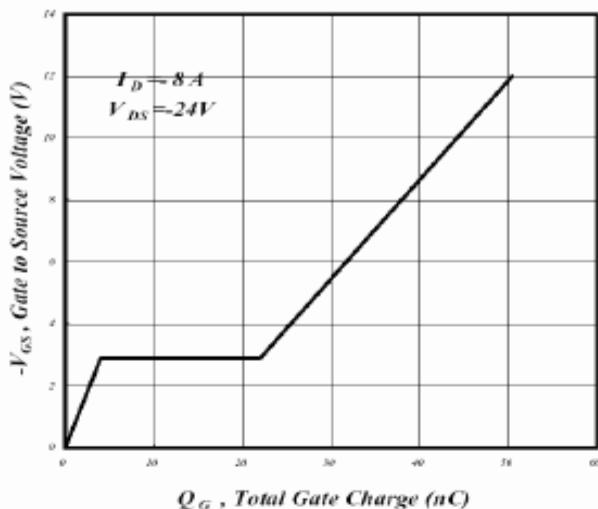


Fig 7. Gate Charge Characteristics

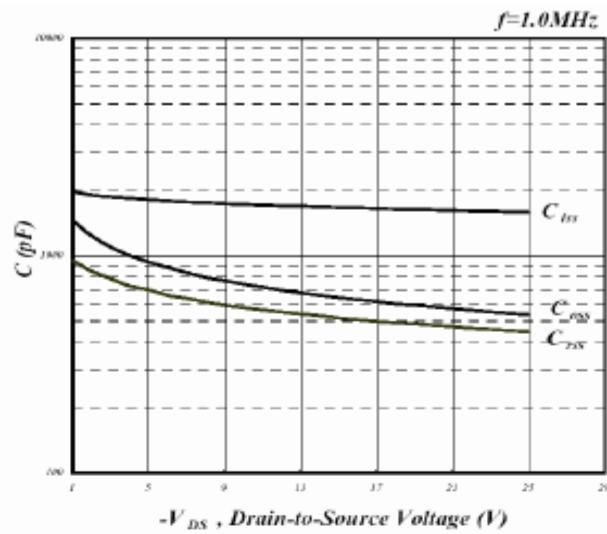


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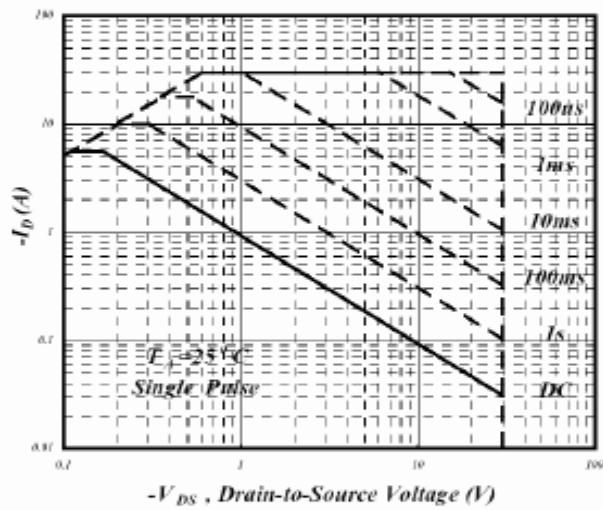


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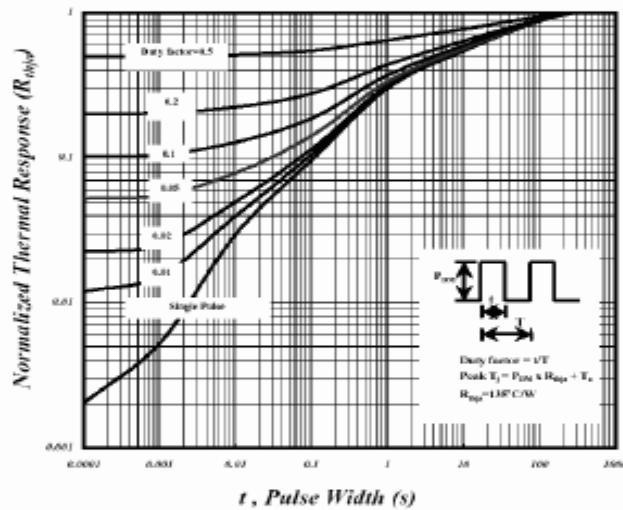


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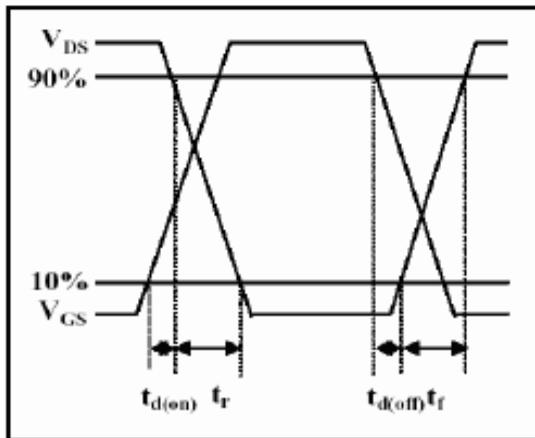


Fig 11. Switching Time Waveform

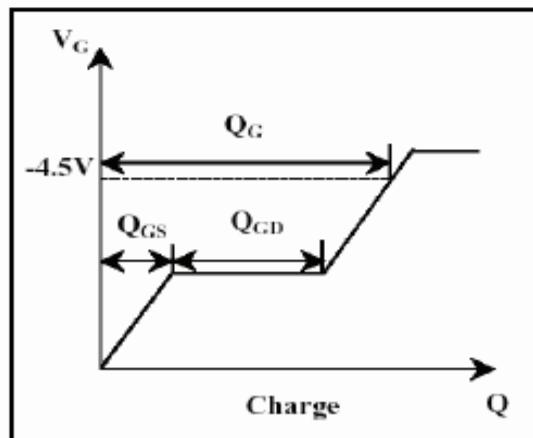
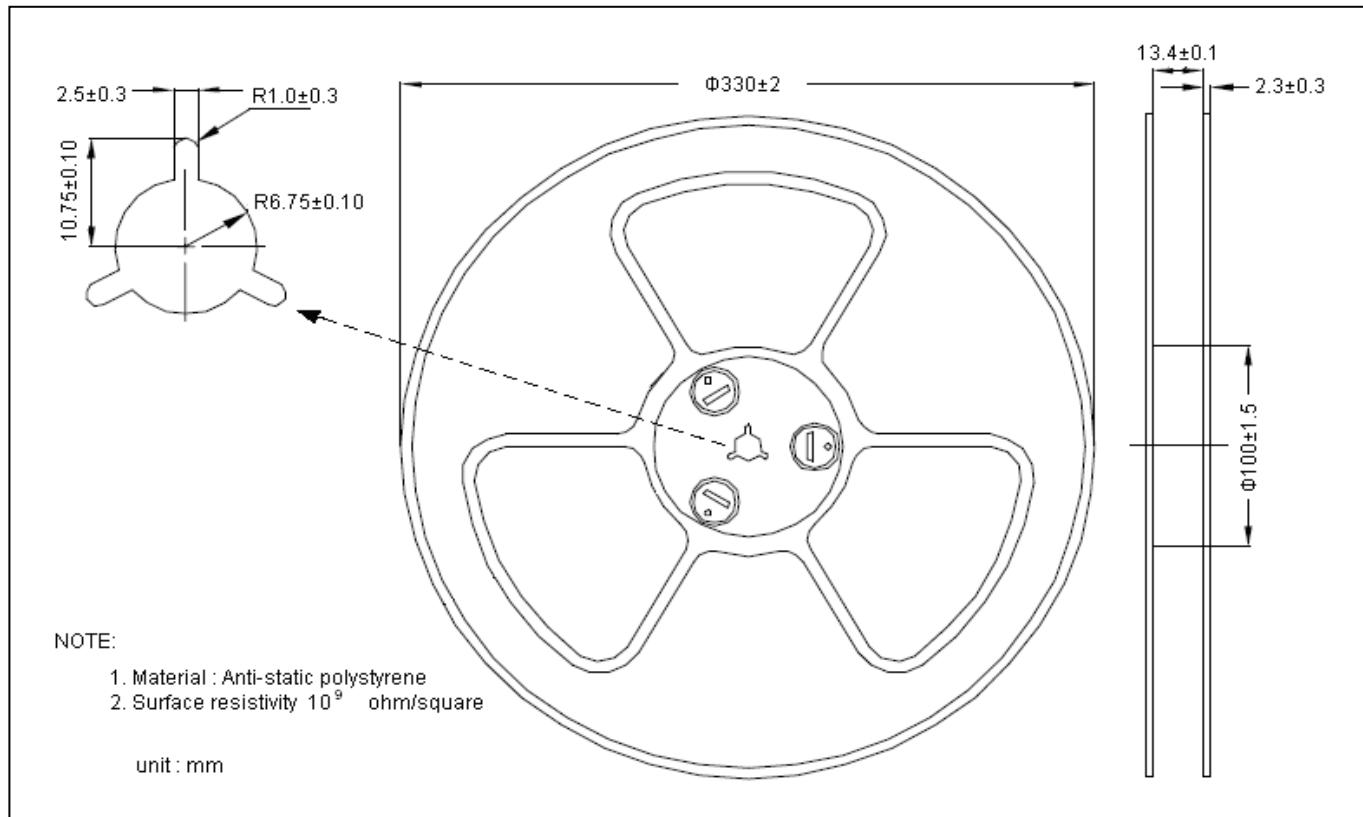


Fig 12. Gate Charge Waveform

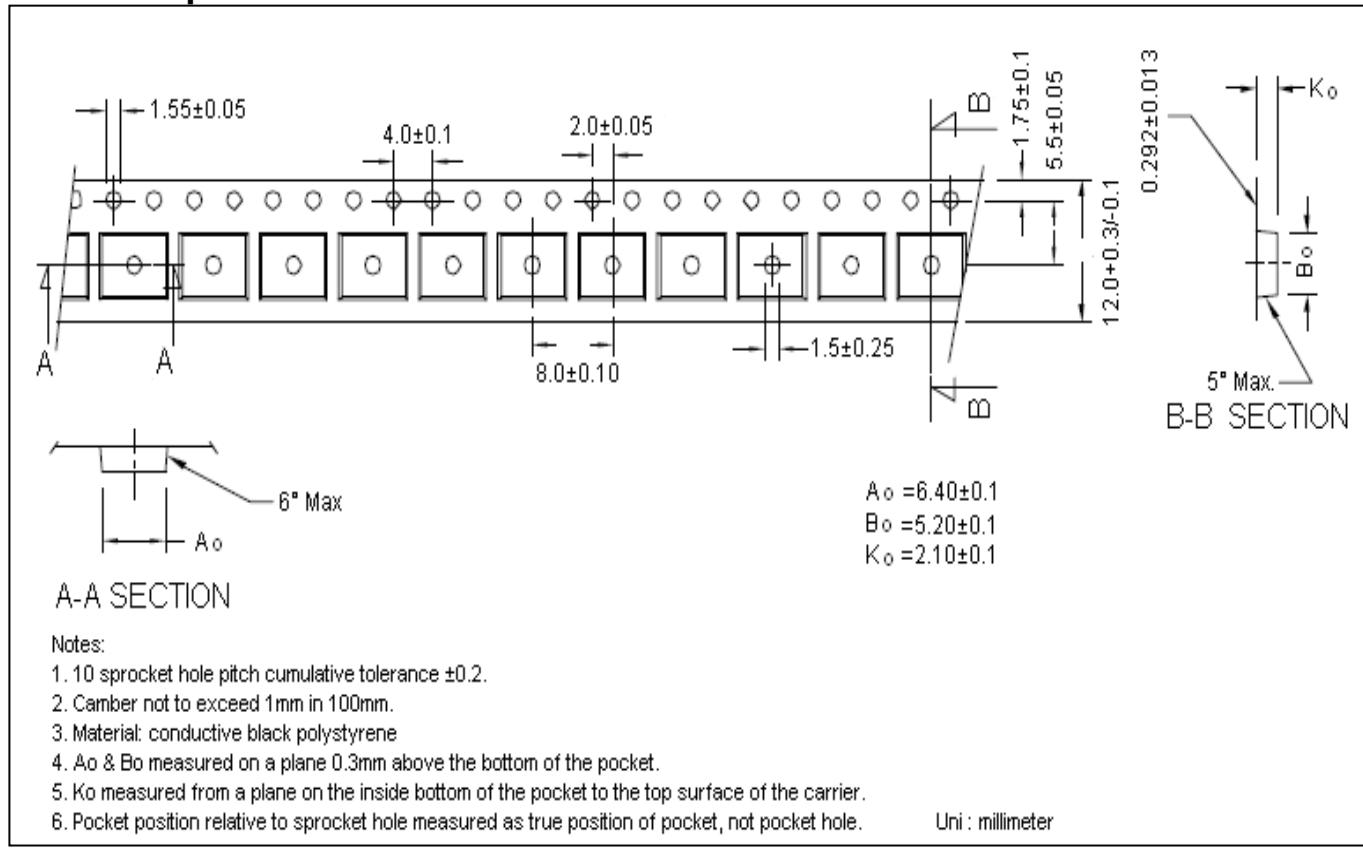
LUL

L4505

Reel Dimension



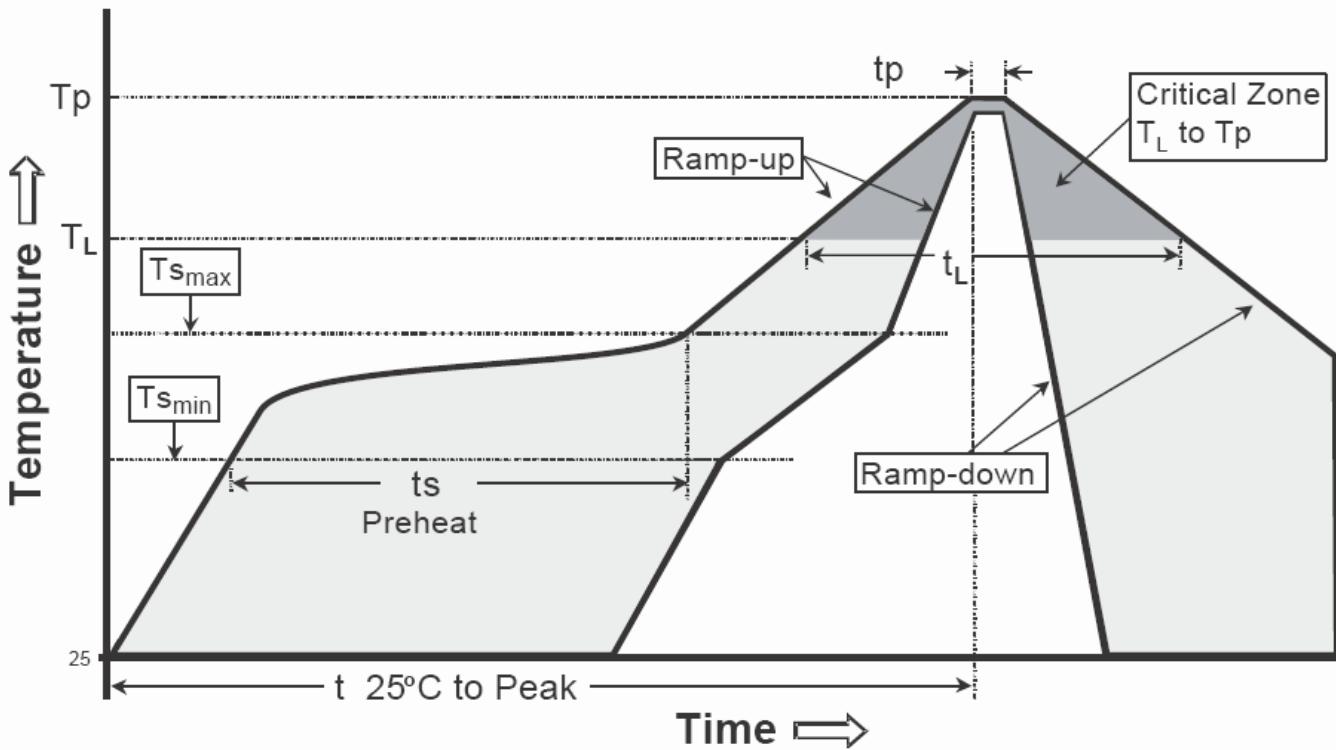
Carrier Tape Dimension



Recommended wave soldering condition

Product	Peak Temperature	Soldering Time
Pb-free devices	260 +0/-5 °C	5 +1/-1 seconds

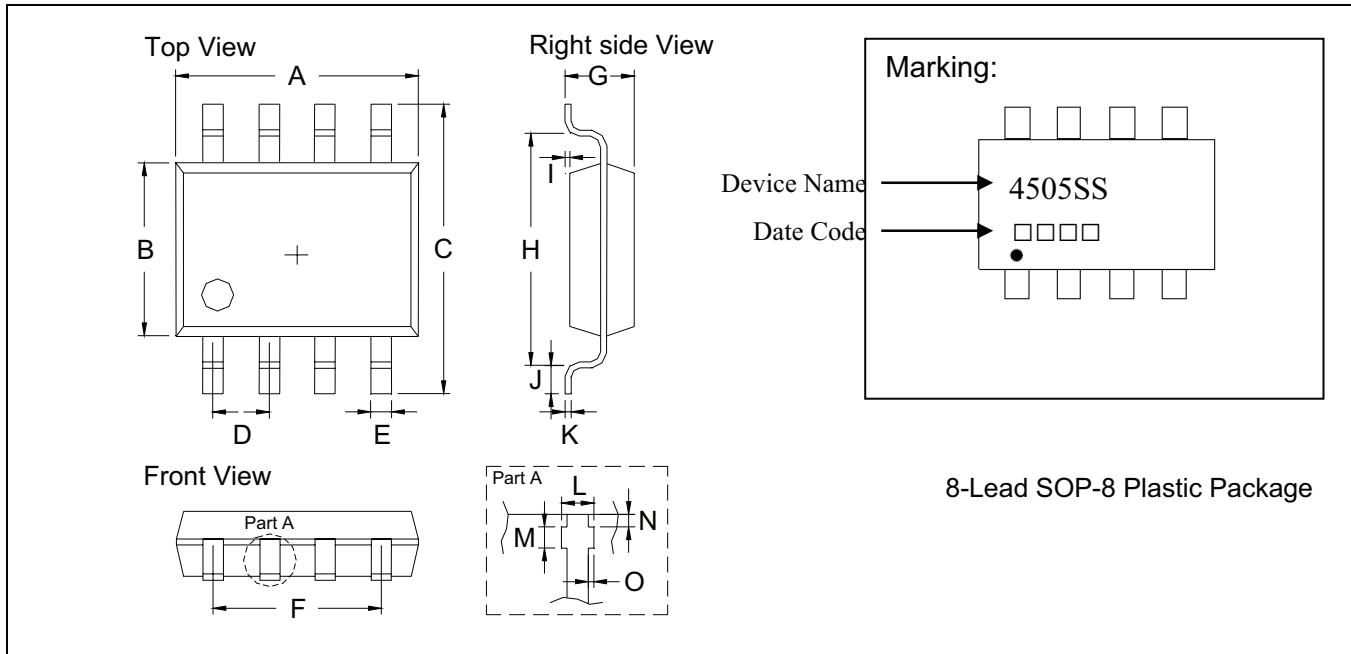
Recommended temperature profile for IR reflow



Profile feature	Sn-Pb eutectic Assembly	Pb-free Assembly
Average ramp-up rate ($T_{s\text{max}}$ to T_p)	3°C/second max.	3°C/second max.
Preheat -Temperature Min($T_s\text{ min}$) -Temperature Max($T_s\text{ max}$) -Time($t_{s\text{ min}}$ to $t_{s\text{ max}}$)	100°C 150°C 60-120 seconds	150°C 200°C 60-180 seconds
Time maintained above: -Temperature (T_L) - Time (t_L)	183°C 60-150 seconds	217°C 60-150 seconds
Peak Temperature(T_p)	240 +0/-5 °C	260 +0/-5 °C
Time within 5°C of actual peak temperature(t_p)	10-30 seconds	20-40 seconds
Ramp down rate	6°C/second max.	6°C/second max.
Time 25 °C to peak temperature	6 minutes max.	8 minutes max.

Note : All temperatures refer to topside of the package, measured on the package body surface.

SOP-8 Dimension



*: Typical

DIM	Inches		Millimeters		DIM	Inches		Millimeters	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
A	0.1890	0.2007	4.80	5.10	I	0.0098	REF	0.25	REF
B	0.1496	0.1654	3.80	4.20	J	0.0118	0.0354	0.30	0.90
C	0.2283	0.2441	5.80	6.20	K	0.0074	0.0098	0.19	0.25
D	0.0480	0.0519	1.22	1.32	L	0.0145	0.0204	0.37	0.52
E	0.0138	0.0193	0.35	0.49	M	0.0118	0.0197	0.30	0.50
F	0.1472	0.1527	3.74	3.88	N	0.0031	0.0051	0.08	0.13
G	0.0531	0.0689	1.35	1.75	O	0.0000	0.0059	0.00	0.15
H	0.1889	0.2007	4.80	5.10					

Notes: 1. Controlling dimension: millimeters.

2. Maximum lead thickness includes lead finish thickness, and minimum lead thickness is the minimum thickness of base material.

3. If there is any question with packing specification or packing method, please contact your local LUL sales office.

Material:

- Lead: Pure tin plated.
- Mold Compound: Epoxy resin family, flammability solid burning class: UL94V-0

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